## **Transfer Matrix Equations**

The Transfer Matrix Equations for an L-layer structure with variations only along the z-axis can be written as

$$\begin{pmatrix} E_1^+ \\ E_1^- \end{pmatrix} = \begin{pmatrix} M_{1,1} & M_{1,2} \\ M_{2,1} & M_{2,2} \end{pmatrix} \begin{pmatrix} E_L^+ \\ E_L^- \end{pmatrix},$$
 (S1)

where the elements  $M_{1,1}$  depend on the material properties (i.e. the refractive index n) and the geometry of each layer, as well as on the frequency and polarization of incident light.

This formalism assumes that layer 1 and L are semi-infinite materials with real refractive indices; however, all intermediate layers have finite thickness and may consist of materials with complex refractive indices. The 2x2 M matrix can be computed from the following product of matrices:

$$\begin{pmatrix} M_{1,1} & M_{1,2} \\ M_{2,1} & M_{2,2} \end{pmatrix} = \mathbf{D}_1^{-1} \left( \prod_{l=2}^{L-1} \mathbf{D}_l \; \mathbf{P}_l \; \mathbf{D}_l^{-1} \right) \mathbf{D}_L.$$
 (S2)

The **P** matrix is defined for each finite-thickness layer as

$$\mathbf{P}_{l} = \begin{pmatrix} \exp(-i \, \phi_{l}) & 0 \\ 0 & \exp(i \, \phi_{l}) \end{pmatrix}, \quad (S3)$$

where  $\phi_l = k_{z,l} \ d_l$  where  $d_l$  is the thickness of the  $l^{th}$  layer of the structure,

$$k_{z,l} = \sqrt{\left(n_l \frac{\omega}{c}\right)^2 - \left(n_l \sin(\theta_1) \frac{\omega}{c}\right)^2},$$
 (S4)

 $\theta_1$  is the angle of incidence of light at frequency  $\omega$  upon the structure and  $n_l$  is the refractive index of the  $l^{th}$  layer at frequency  $\omega$ . If the incident light is s-polarized, then the **D** matrix for the  $l^{th}$  layer has the form

$$\mathbf{D}_{l} = \begin{pmatrix} 1 & 1 \\ n_{l}\cos(\theta_{l}) & -n_{l}\cos(\theta_{l}) \end{pmatrix}, \quad (S5)$$

while if the light is p-polarized, the **D** matrix for the  $l^{th}$  layer has the form

$$\mathbf{D}_{l} = \begin{pmatrix} \cos\left(\theta_{l}\right) & \cos\left(\theta_{l}\right) \\ n_{l} & -n_{l} \end{pmatrix}, \quad (S6)$$

where  $\theta_l$  is the refraction angle in the  $l^{th}$  layer determined by Snell's law.

The amplitudes  $E_1^+$  and  $E_1^-$  are interpreted as the incoming and outgoing wave amplitudes on the incident side, respectively; similarly,  $E_L^-$  and  $E_L^+$  are interpreted is the incoming and outgoing wave amplitudes on the terminal side, respectively. With access to the field amplitudes and wavevectors, a number of useful quantities may be computed. For example, the Fresnel reflection and transmission amplitudes may be computed as  $r = \frac{E_1^-}{E_1^+}$  and  $t = E_L^+$ . For the analysis of reflection experiments,  $E_1^+ = 1$  and  $E_L^- = 0$  by convention. Consideration of Eq. (S1) under these conditions leads to expressions for the reflection and transmission amplitudes in terms of the elements of the **M** matrix,

$$r = \frac{M_{2,1}}{M_{1,1}} \qquad (S7)$$

$$t = \frac{1}{M_{1.1}}.$$
 (S8)

The reflection can then be calculated as  $R = |r|^2$ , the transmission as  $T = |t|^2 \frac{n_L \cos(\theta_L)}{n_1 \cos(\theta_1)}$ . The absorption at a given frequency, which can be taken to be equal to the emissivity by Kirchoff's law, can simply be computed as  $\epsilon(\omega) = A(\omega) = 1 - T(\omega) - R(\omega)$ . The transfer matrix equations can be used to compute the stored energy of the Bragg Relector  $(P_{BR}(\omega))$  as well, which is a key quantity for assessing the degree of critical coupling. Following the discussion by Piper and Fan, the amplitude associated with the stored energy in a lossless resonant reflector  $(E_S)$  can be related to the incoming and outgoing wave amplitudes according to

$$E_S = \left| \frac{E_1^- + E_1^+}{\sqrt{2\gamma_I}} \right|^2 \qquad (S9)$$

where  $\gamma_l$  is the leakage rate associated with the Bragg reflector. From Eq. S1, the stored energy spectrum can be calculated for a given frequency as

$$E_S = \frac{(r+1)(r^*+1)}{2\gamma_l}.$$
 (S10)